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# Ultra-thin, transparent and flexible tactile sensors based on graphene films with excellent anti-interference†

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Tactile sensing, which can reflect the displacement of touch, is considered to be an essential function for electronic skin to mimic natural skin. Here we report a novel tactile sensor with good sensitivity, excellent durability and fast response based on highly flexible and transparent conductor layers. The tactile device is simple in terms of structure consisting of a pair of compliant conductive plates, which were adhered to graphene films (GFs) on the surface layer of the polyethylene terephthalate (PET) substrate, and a transparent elastic adhesive sandwiched between the electrodes. The as-assembled tactile sensors can reflect one-dimensional (1D) touch tactile. And the resistance of the device is linearly related to the tactile of touch. Notably, the rate of resistance change is up to 420% when the displacement is changed by 25 mm. The tactile sensor features a high sensitivity of 0.143 mm<sup>-1</sup>, a long lifetime of 14 000 cyclic loading tests, and a fast response of 0.3 ms. Furthermore, the electrical signals of the tactile sensors are almost irrelevant to the interference signals such as vertical displacement, stress magnitude, stress acting area and bending strain. This rational design of innovative materials and devices presents great potential for electronic devices to completely replace the unique tough sensing properties of human skin.

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## 1. Introduction

The development of touch sensing is an engineering challenge for next-generation robotics and human-machine interfaces since the emulation of touch requires large-scale tactile sensors with high sensitivity, good stability and fast response.<sup>1–8</sup> Some tactile systems fabricated with tactile pressure sensor arrays have been reported,<sup>9–19</sup> whose working mechanism is based on changes in capacitance or resistance. While with a resolution on the millimeter order, these devices have not yet met the requirements of electronic skins whose spatial resolution is near 50 μm. And the doubling of the electrode number led to tactile systems that must be packed with increasingly sophisticated circuitry. A spatial resolution of 120 μm was achieved for a piezotronic pressure sensor array,<sup>20,21</sup> and an ultrahigh resolution of 2.7 μm was derived from a piezophotronic pressure sensor array using a ZnO nanowire/p-GaN LEDs array.<sup>22,23</sup> However, the lack of flexibility with a stiff and brittle substrate prevents these array devices from being suitable for the human body, and the transparency of the devices is in a relatively low region. Very

recently, a highly stretchable and transparent ionic touch strip based on a polyacrylamide hydrogel containing lithium chloride salts was reported in *Science*.<sup>24</sup> The touch strip successfully eliminated the complex multielectrode, but the sensitivity of the tactile sensor was really poor with a resolution on the order of 10<sup>-4</sup> m, and the anti interference property of the device is not satisfactory (tensile strain has a great impact on the device's sensitivity). Therefore, a flexible and transparent tactile sensor with high sensitivity becomes imperative which will has numerous potential applications in human-machine interfaces.

In this paper, we present a new kind of skin-like transparent tactile sensors based on graphene films (GFs) and PET. The fabrication of our tactile sensor is very simple but exhibits high sensitivity, short response time and excellent cycling stability. The high sensitivity is demonstrated to be 14.3% mm<sup>-1</sup>, which is ten times (~10<sup>-5</sup> m resolution) of the similar functional device recently reported in *Science*. More significantly, the tactile sensor demonstrate an outstanding performance against the interference signals such as vertical displacement, stress magnitude, stress acting area and bending strain. This interesting property of touch sensors has not been explored before. The device is transparent and bio-friendly compatible enough to be placed on human skin.

## 2. Experimental

### 2.1. Synthesis of GFs

Copper foil (20 mm × 40 mm × 25 μm, Alfa Aesar) were cleaned, tailored, and pretreated as reported previously. When

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the temperature reached 1000 °C, H<sub>2</sub> was turned up to 20 cm<sup>3</sup> min<sup>-1</sup> and reactor's pressure was pumped down to 20 Pa. CH<sub>4</sub> was cut off for 15 min due to thermal annealing of copper foil, and then turned up to 5 cm<sup>3</sup> min<sup>-1</sup>. After 30 min growth, the foil was rapidly cooled down to room temperature. Graphene films were grown on the copper substrate. After spin coated PMMA gel and dried, GFs-PMMA could be obtained when copper foil was etched away by an aqueous solution of (NH<sub>4</sub>)<sub>2</sub>S<sub>2</sub>O<sub>8</sub> (0.5 mol L<sup>-1</sup>) and NH<sub>3</sub>·H<sub>2</sub>O (0.5 mol L<sup>-1</sup>).

## 2.2. Fabrication of GFs-PET multilayer stacked tactile sensor

The fabrication of GFs/PET conductive plate is described as follows: the PET substrate was cleaned, tailored and plasma etching in order to keep the surface smooth and uniform. And then GFs-PMMA obtained previously was spread onto the PET uniformly, dried at 60 °C for 30 min to remove water at atmospheric pressure ( $\approx 100 \mu\text{m}$  thick). After soaking in acetone solution for 8 hours to remove the PMMA gel away from the GFs, the conductive plate was cut into half along length and silver wires were connected using silver paste to the edge of GFs. Then, a pair of above conductive plates was stuck together by the highly transparent acrylic tape ( $\approx 120 \mu\text{m}$  thick, TESA 4965PV0) and ensure that the graphene surface opposite. Afterwards, the tactile sensors were assembled ( $\approx 320 \mu\text{m}$  thick).

## 2.3. Characterizations and testing

The Raman spectrum was obtained by utilizing confocal Raman spectroscopy (Horiba JY-HR800) with an Ar<sup>+</sup> laser source at room temperature. Field emission scanning electron microscope (FESEM, SUPRA55) was employed to observe the morphology of synthesized materials. The transmittance test was carried out on Ultra-violet and Visible Spectrophotometer (Technical Institute of Physics and Chemistry CAS). The pressure loading was achieved through a cantilever cutter head. The electrical properties were recorded by a digital source meter (Keithley DMM-7510), and the source-drain voltage.

## 3. Results and discussion

Fig. 1a describes the schematic representation of the key processes in manufacture and operation of a transparent tactile sensor based on GFs-PET conductive plates. Herein, the graphene films were obtained by low pressure chemical vapor deposition (CVD) method through growing graphene on the copper foil substrate.<sup>25</sup> Afterwards, the graphene films (GFs) were transferred to the FET substrate from the copper foil by the wet transfer method.<sup>26–28</sup> The GFs-PET plate was cut evenly into two portions along the longitudinal direction and the silver colloid electrodes were made at the edge of graphene. Then, a pair of above conductive plates was stuck together by a highly transparent acrylic tape and ensure that the graphene surface opposite. The multi-layer sensors were then finally fabricated. From the image shown in Fig. 1b, the tactile sensor was rather thin and could be bent with excellent flexibility. As shown in Fig. S1,<sup>†</sup> the size of the transferring graphene film was 40 mm ×

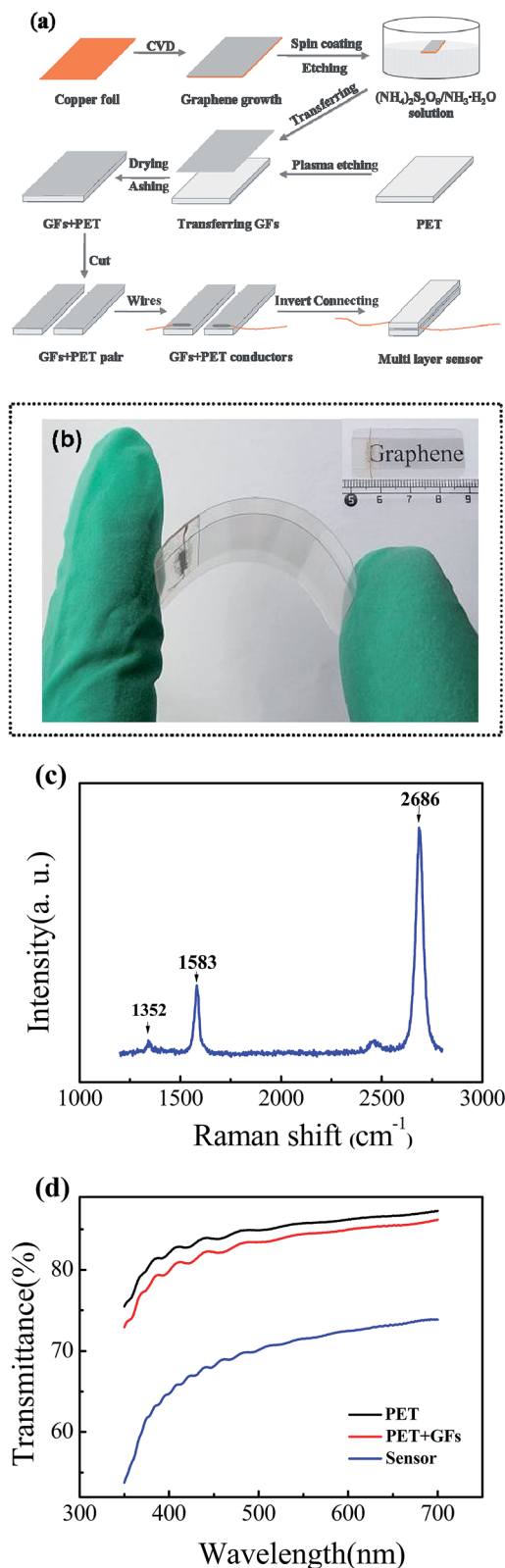


Fig. 1 (a) Schematic diagram of fabrication procedure of a tactile sensor based on GFs and PET plate. (b) Optical photograph of a bent assembled sensor. The geometric dimension of the sensor is shown in the inset. (c) Raman shift of the GFs with a typical D  $\approx 1352 \text{ cm}^{-1}$ , G  $\approx 1583 \text{ cm}^{-1}$  and 2D  $\approx 2686 \text{ cm}^{-1}$  peak. (d) Transmittance spectra of pure PET, GFs-PET composite structure and multilayer stacked nano-film sensor in the visible wavelength range from 350 to 700 nm.



20 mm. The geometric dimension of the sensor is shown as an inset in the Fig. 1b and the effective size of graphene is about 30 mm × 10 mm.

The Raman spectrum (Horiba JY-HR800) of the graphene films shown in Fig. 1c demonstrates the characteristic peaks of 1352, 1583, and 2686 cm<sup>-1</sup>, which is correspondence to the D, G, and 2D band of graphene, respectively. As shown in the Raman spectrum, the typical intensity ratio of prominent peak 2D and G ( $I_{2D}/I_G$ ) is approximately greater than 2, which confirmed that the graphene had a single layer structure. The Fig. S2 in the ESI† indicated that the graphene was a continuous film. Fig. 1d depicts the transparency comparison (Technical Institute of Physics and Chemistry CAS) of a pure PET, GFs-PET composite structure and multilayer stacked nano-film sensor, respectively. The optical transmittance of the fabricated sensor is about 70% in the visible range, which provides optical transparency enough for an aesthetic view of the human body. Compared with previously reported wearable sensors, the optical transmittance of our sensors is favorably comparable with recent values of other graphene-based sensors (~70%),<sup>29</sup> and slightly better than those nanocomposite devices (63–68%),<sup>30,31</sup> and far superior than that previously reported (<20%).<sup>32</sup>

Fig. 2a is a schematic illustration of the tactile sensor. As presented in Fig. S3,† though the tactile sensor was multilayered, the total thickness was only about 320 μm (which is around 60% of the thickness of the human epidermis). The resistance variation of the total sensor is monitored during applying constant pressure (a conical shaped indenter weighted 0.25 N) while continuously increasing the distance between pressure and initial tactile.

The principle of the device for displacement detection is as same as the sliding rheostat. Each device can be treated as a resistor with the resistance  $R$  given by:

$$R = R_1 + R_2 + R_a \quad (1)$$

where  $R_1$  and  $R_2$  are the resistance of the top and bottom GFs-PET conductive plate, respectively. The resistance  $R_a$  is the contact part between the two conductive plates which is infinite under no pressure. The  $R_a$  is the sum of the two graphene films' vertical resistance and the contact resistance between the two layers. During the test, the  $R_a$  is a fixed value because the vertical resistance and layers' contact resistance will not change when the pressure applied in the same way. Thus, the resistance  $R$  of the entire sensor is decided by  $R_1$  and  $R_2$  which satisfied the following equation

$$R = \rho \frac{l}{s} \quad (2)$$

where  $\rho$  means resistivity,  $l$  means effective length and  $s$  means the cross-sectional area of the GFs-PET conductive plate. In principle, the resistivity and cross-sectional area are constant physical quantities during the operation of the device. Therefore, the resistance of the conductive plate is proportional to  $l$ . When the point of pressure moves away from one end of the electrode, the effective length  $l$  will increase resulting in the

increase of the plate resistance  $R_1$  and  $R_2$ . That means the sensor resistance  $R$  may have the linear relationship with the distance  $l$  between the pressure point and the electrodes.

Fig. 2b shows the tactile sensing function of our sensor. The resistance  $R$  is only 3.19 kΩ when the pressure acting on the end of electrode which is defined as the origin tactile  $l = 0$  mm. Then, the resistance of the sensor increases as long as the distance  $l$  increases, and at last reached up to 16.87 kΩ at the distance  $l = 25$  mm. Obviously, the resistance  $R$  possesses a linear dependence on the distance and the slope of the fitting curve is about 455.09 Ω mm<sup>-1</sup>. Moreover, the tendency of the two curves show high coincidence between  $l_1$  (increase the distance, original state) and  $l_2$  (decrease the distance, after 10 000 loading cycles), indicating excellent reproducibility. The jump of the curve at 5 mm may be caused by the damage of graphene films. We set  $R_0$  for the initial resistance of the sensor when the pressure acting on the origin tactile.  $\Delta R$  is defined as the deference between the initial resistance  $R_0$  and the resistance  $R$  measured in real time.

The Fig. 2c shows the fractional change in resistance  $\Delta R/R_0$  reached up to 420% at the distance  $l = 25$  mm. And  $\Delta R/R_0$  shows a linear dependence on the pressure tactile. According to previous literature,<sup>33</sup> tactile sensitivity  $S$ , defined as the slope of the traces, which is commonly used to evaluate the performance of the sensor as below:

$$S = \frac{(R - R_0)/R_0}{l} = \frac{\Delta R/R_0}{l} \quad (3)$$

As shown in Fig. 2c, the tactile sensitivity of our sensors is 0.143 mm<sup>-1</sup>, which means the fractional change in resistance will up to 14.3% when the pressure tactile changes 1 mm.

In the following experiments, several typical pressures tactile such as 5 mm, 10 mm, 15 mm and 20 mm, are measured with a pressure of about 0.25 N. A pressing stimulus was applied by an indenter ( $m = 25$  g) to introduce a contact between the top and bottom GFs-PET conductive plate. Fig. 2d shows the response of the device upon loading/unloading the force and the stable resistance response indicate that the device exhibits an excellent mechanical robustness and the reliability. It is well known fast response time is important in realizing real-time tactile monitoring. Here, the response time (rise time) is defined as the time interval between 10% and 90% of the steady state values of resistance. As shown in the inset of Fig. 2e, the response time of our tactile sensor was estimated to be about 0.3 ms. Compared with previously reported resistive sensors, the response time of our sensors is favorably comparable with recent values of other nanocomposite sensors (0.4 ms),<sup>34</sup> and faster than those flexible devices (4–17 ms),<sup>29,35–37</sup> and far superior than that previously reported (90–200 ms).<sup>38–40</sup> To further investigate the stability of the tactile sensor, the resistance changes of the sensor were measured when repeatedly load/unload an applied pressure of human finger for more than 14 000 cycles (2 s for each cycle). The result is shown in Fig. 2f, which reveals that the tactile sensor exhibits high durability. Above all, our fast responsibility sensor is adequate to be used



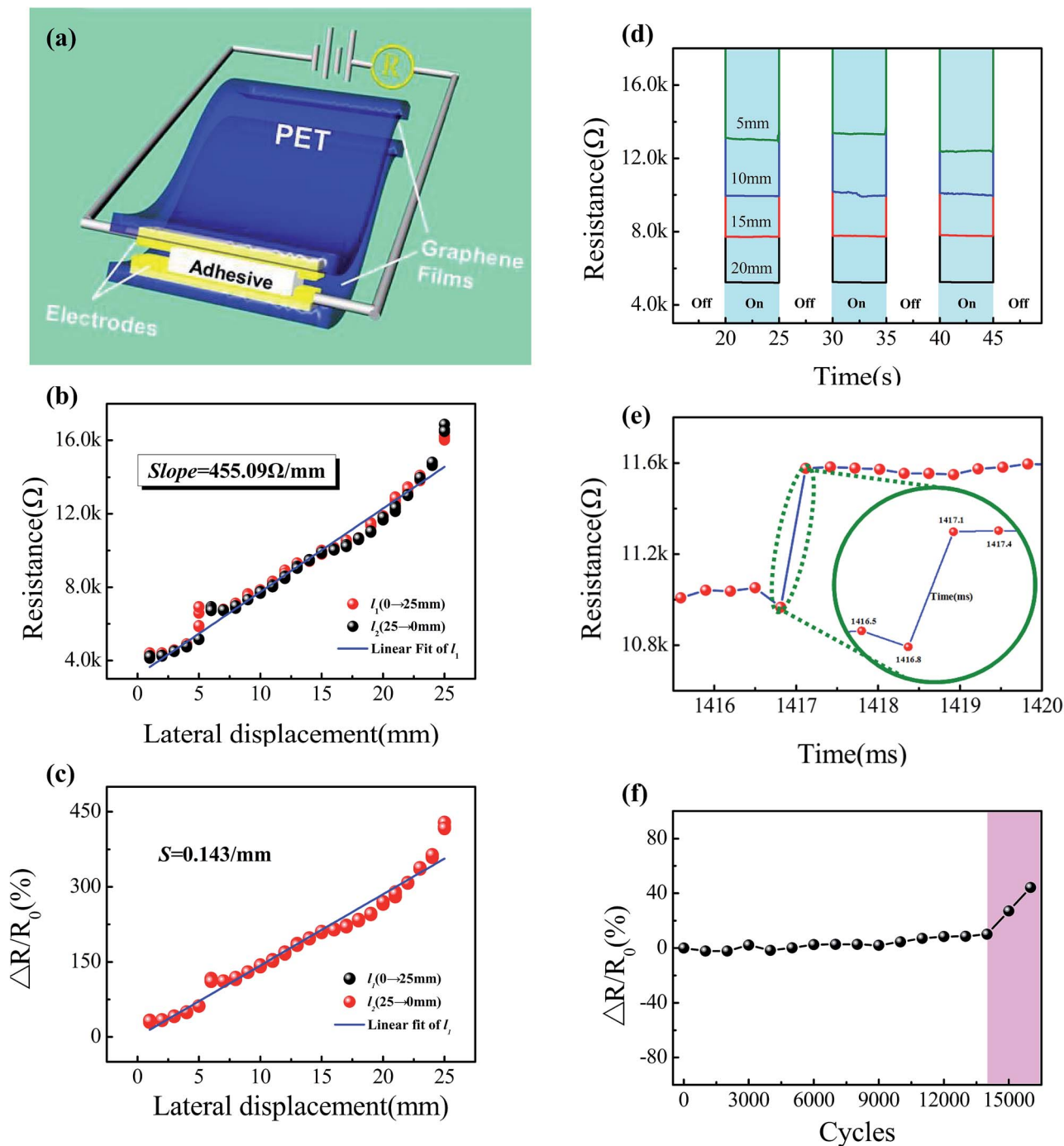


Fig. 2 (a) Schematic illustration of the tactile sensor consisting of the stacked nano-hybrid structure. (b) A typical sensor's characteristic of resistance change with an increase (red line)/decrease (black line) in distance. (c) Distance-dependent  $\Delta R/R_0$  of the sensor at distance ranging from 0 mm to 25 mm. (d) Time-dependent resistance change of the sensor in response to distance of 5 mm, 10 mm, 15 mm, and 20 mm at repetitive cycle stress. (e) Time response characteristic of the tactile sensor. According to the enlarged illustration, the response time is 0.3 ms. (f) The stability of the tactile sensor for more than 14 000 loading/unloading cycles, at 2 s for each cycle, with an applied pressure of human finger.

in electronic and circuit system, wearable sensors and mechanical applications.

As a tactile sensor, the response of a device to the tactile of pressure must be specific. That means during the pressure applied only the displacement which is the target detection signal will cause a significant change in resistance. Any other signals caused by pressure, regarded as interference signals

such as vertical displacement, stress magnitude, stress acting area and bending strain, can not lead to obvious resistance signal in the detection process. This is the key to ensure the reliability of the accurate tactile.

To investigate the reliability of the devices for tactile sensing, we measured the properties of our sensors under the interference. The anti interference against the longitudinal change of



the pressure tactile at the horizontal coordinate of 5, 10, 15 and 20 mm is shown in Fig. 3a. The width of the sensor was 10 mm. The touch points with the same distance from the electrode must have the same resistance. That means if the sensor was in a two-dimensional coordinate system and the touch movement in the  $X$  axis will cause the change of resistance while no change in the  $Y$  axis. This protects the sensor from output wrong signal while touch movement appeared in the  $Y$  axis. The real-time resistance curves had no markedly interference and the fractional change in resistance  $\Delta R/R_0$  was only 0.1%, which was much lower than the sensitivity of our sensors (14.3%). This result comes from the uniformity of the graphene films that ensures the resistance distribution was uniform.

Fig. 3b presents the immunity of the GFs-PET composite conductor to the tensile (black column) and compressive (red column) strain. The bending test was just for single plate. The resistance of the conductive plate was increased under tensile strain, but decreased under compressive strain. However, the fractional change in resistance  $\Delta R/R_0$  shows a slight variation ( $\sim 0.3\%$ ) that is much smaller than the sensitivity of tactile sensing even if the bending strain increases up to 4.3‰. An inset shown in Fig. 3b described the total sensor under bending with the strain from 1.1‰ increasing to 4.3‰. The maximum rate of change in resistance appeared in strain 4.3‰ was only 0.08%, which was even lower than a single conductive plate under the bending strain 1.1‰ ( $\sim 0.13\%$ ). Because the sensor was a double layer structure, the two conductive plates were always under bend strain with the same value but opposite direction. Therefore, the bend strain of the total sensor was always smaller than that of any one plate.

On the other hand, the resistance responses of sensor to other interfering signals such as stress magnitude (Fig. 3c) and stress acting area (Fig. 3d) were little sensitive. Initial resistance  $R_0$ , was designated as the resistance at distance of 14 mm where applied a constant pressure of 0.25 N. After the extra pressure increased from 0 to 2 N, the fluctuation of the resistance change rate kept in a very small range ( $< 1.1\%$ ). Similarly, we also evaluated the anti interference of the sensor to the stress acting area as shown in Fig. 3d. The stress acting area of slide (2 mm  $\times$  15 mm) was defined as original area  $s$ , and it was increased up to 5-fold larger by adding up numbers of slides with the same geometric size. In particular, the increase of the stress area is only added to the same side of the initial slide that away from the electrodes, which is to ensure that the effective length  $l$  is constant.  $R_a$  is the sum of the two graphene films' vertical resistance and the contact resistance between the two layers. The graphene film is a monolayer film so that the carrier scattering in the vertical direction is very small. On the other hand, the plate is not flat on the micrometer scale and the contact of two plates can be seen as numerous "point contact". Obviously, the contact resistance (affected by the number of contact points) of the two plates makes the greatest contribution to the  $R_a$ . So, when the surface area is constant, the number of contact points increases with the pressure increases, this resulting in a slight reduction in sensor resistance. The contact points will increase as the contact area increased, leading to the increase of the carrier number passing through the "contact points" during the

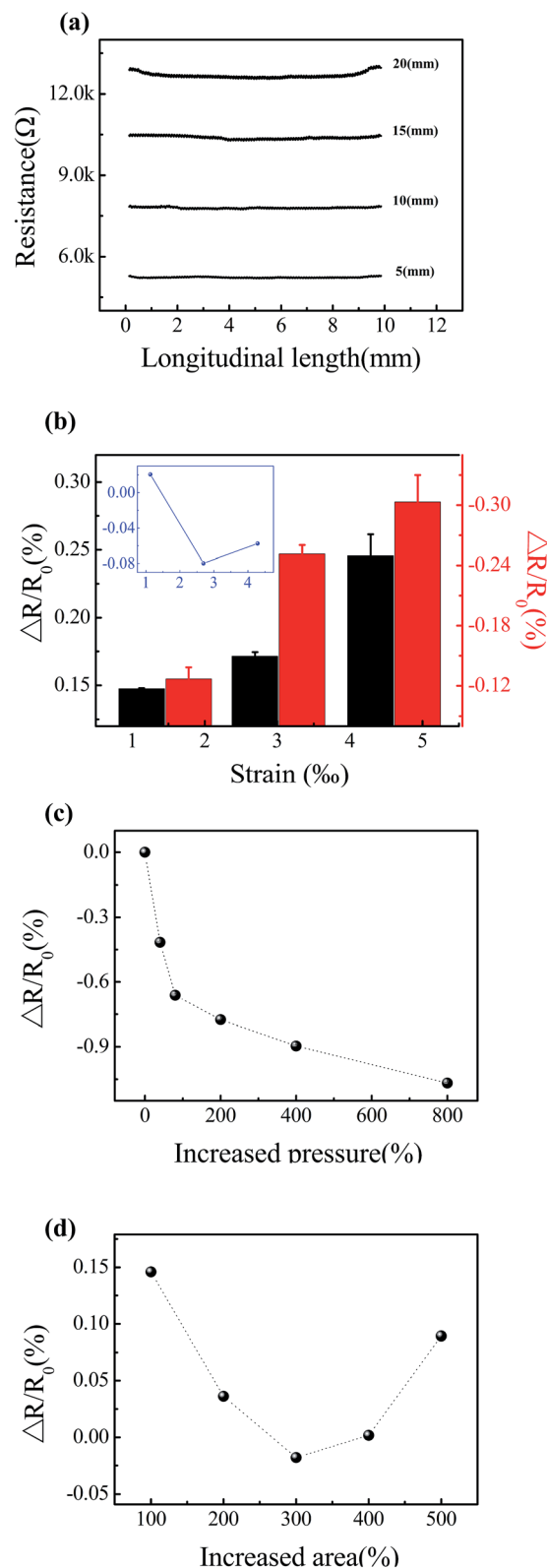


Fig. 3 (a) Sensitivity of the device to longitudinal displacement at different axial distance of 5 mm, 10 mm, 15 mm, 20 mm. (b) Stability of the tactile sensor to the applied tension (black column) and compression (red column) strain. (c) Stability of the tactile sensor to the increased pressure. (d) Stability of the tactile sensor to the increased force area.



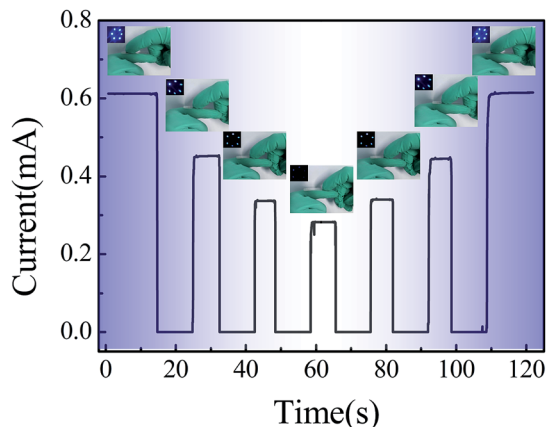


Fig. 4 Wearable graphene-based sensor for finger pressure tactile detections. The variation of the LED connected in the external circuit and the finger movements are shown in the illustration.

unit time, resulting in a slight reduction in the sensor resistance. While the increased bending strains of the plate at the same time will increase the sensor resistance. So the combined result of the two changes in the surface area variation test will be obtained:

$$R' = R_1 + R_2 + \frac{R_a}{6} \quad (4)$$

There is a difference of  $5R_a/6$  compared to the original resistance  $R$  given by formula (1). However, the fractional change in resistance  $\Delta R/R_0$  of area change showed a slight variation ( $<0.15\%$ ) that was much smaller than the sensitivity of tactile sensing (14.3%). Consequently, the results indicate that the tactile sensor has an outstanding anti interference against the stress acting area because the resistance  $R_a$  is small enough to be negligible compared to  $R_1$  and  $R_2$ .

Application of the graphene-based tactile sensors for human machine interface (HMI) transmission is demonstrated. The sensor serves as a flexible and transparent touch strip, as shown in Fig. 4. The LED lights were series connected in the circuit, in order to show a significant variation when the pressure finger moved from the finger root to the tip under the bias voltage of 10 V. When the finger moved back, the brightness of LED lights will be restored.

## 4. Conclusions

In summary, a wearable tactile sensor was assembled with the multilayer stacked nano-films structure of PET-GFs/GFs-PET. Notably, the graphene-based sensors do not only feature an impressively high sensitivity of  $0.143 \text{ mm}^{-1}$  for tactile sensing, but also show the strong anti-interference ability to the interference signals such as vertical displacement, stress magnitude, stress acting area and bending strain. After repeatedly load/unload an applied pressure of 0.25 N for more than 14 000 cycles (2 s for each cycle), the sensors still demonstrate the high tactile sensing ability within relative resistance variability of

9.98%. The tactile sensors are able to control electronic circuit with fast response time of  $\sim 0.3 \text{ ms}$ , which is fairly comparable or superior to recent studies of other resistive sensors. Prototype devices were also demonstrated by attached the tactile sensor onto a little finger for touch tactile detection. Our sensors have a great advantage in transparency and flexibility when compete with the conventional metal and semiconductor tactile devices. And compared with the recently tactile sensor arrays, the graphene-based device is easy to fabricate and wearable without integration. We believe that the facile, low-cost and readily scalable method allows practical fabrication of graphene-based tactile sensors for emerging human-interactive applications.

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